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## (12) United States Patent Chu

(10) Patent No.: US 7.056.866 B1 Jun. 6, 2006 (45) Date of Patent:

#### (54) SUPERCONDUCTIVITY IN SOUARE-PLANAR COMPOUND SYSTEMS

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Park, Houston, TX (US) (\*) Notice: Subject to any disclaimer, the term of this patent is extended or adjusted under 35 U.S.C. 154(b) by 785 days.

(21) Appl. No.: 07/032,041

#### (22) Filed: Mar. 26, 1987

## Related U.S. Application Data

(63) Continuation-in-part of application No. which is a continuation-in-part of application No. 07/006,991, filed on Jan. 26, 1987, now abandoned, which is a continuation-in-part of application No. 07/002,089, filed on Jan. 12, 1987, now abandoned.

C04B 101/00 (2006.01)

H01L 39/12 (2006.01) (2006.01) H01B 12/00

505/125; 505/126; 505/490; (52) U.S. Cl. .... 505/500; 505/780

(58) Field of Classification Search 252/520, 252/521, 518; 423/263, 593; 501/104, 108, 501/123, 126, 135, 152; 29/599; 420/901; 428/930; 505/100, 125, 126, 779, 780, 490, 505/500

See application file for complete search history.

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#### ABSTRACT

Described is a superconducting composition comprising an oxide complex of the formula [L, M,], A,O, wherein L is lanthanum, lutetium, yttrium, or scandium; A is copper, bismuth, titanium, tungsten, zirconium, tantalum, niobium, or vanadium; M is barium, strontium, calcium, magnesium or mercury; and "a" is 1 to 2; "b" is 1; and "x" is a number in the range of 0.01 to 1.0; and "y" is about 2 to about 4. The oxide complexes of the invention are prepared by a solid-state reaction procedure which produces an oxide complex having an enhanced superconducting transition temperature compared to an oxide complex of like empirical composition prepared by a coprecipitation—high temperature decomposition procedure. With an oxide complex prepared by the solid-state reaction of the invention a transition temperature as high as 100°K has been observed even under atmospheric pressure.

### 15 Claims, 5 Drawing Sheets

